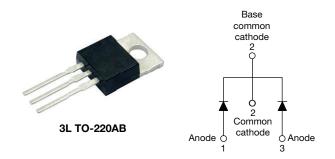
Vishay Semiconductors

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Ultrafast Rectifier, 2 x 10 A FRED Pt[®]



| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|----------------|--|--|--|--|--|
| Package 3L TO-220AB | | | | | | |
| I _{F(AV)} | 2 x 10 A | | | | | |
| V _R | 200 V | | | | | |
| V _F at I _F | 0.85 V | | | | | |
| t _{rr} typ. | 19 ns | | | | | |
| T _J max. | 175 °C | | | | | |
| Circuit configuration | Common cathode | | | | | |

FEATURES

- Ultrafast recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Designed and gualified according to JEDEC[®]-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

VS-MUR2020CT-M3 is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|---|--------------|-----------------------------------|--|-------------|-------|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | MAX. | UNITS | | | |
| Peak repetitive reverse voltage | | V _{RRM} | | 200 | V | | | |
| Average restified forward surrant | per leg | E(A)A | | 10 | | | | |
| Average rectified forward current | total device | | Rated V _R , T _C = 145 °C | 20 | | | | |
| Non-repetitive peak surge current per leg | | I _{FSM} | | 100 | A | | | |
| Peak repetitive forward current per leg | | I _{FM} | Rated V _R , square wave, 20 kHz, $T_C = 145 \text{ °C}$ | 20 | | | | |
| Operating junction and storage temperatures | | T _J , T _{Stg} | | -65 to +175 | °C | | | |

| ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | | |
|--|-------------------------------------|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 200 | - | - | | | |
| Forward voltage | V _F | I _F = 8 A, T _J = 125 °C | - | - | 0.85 | V | | |
| | | I _F = 16 A | - | - | 1.15 | | | |
| | | I _F = 16 A, T _J = 125 °C | - | - | 1.05 | | | |
| Reverse leakage current I _R | | $V_{R} = V_{R}$ rated | - | - | 15 | | | |
| | | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | - | - | 250 | μA | | |
| Junction capacitance | CT | V _R = 200 V | - | 55 | - | pF | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH | | |

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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | | |
|---|------------------|---|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| | | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$ | 50 A/µs, V _R = 30 V | - | - | 35 | | | |
| Reverse recovery time | + | $I_F = 0.5 \text{ A}, I_R = 1.0$ | I _F = 0.5 A, I _R = 1.0 A, I _{REC} = 0.25 A | | - | 25 | | | |
| | t _{rr} | T _J = 25 °C | | - | 21 | - | ns | | |
| | | T _J = 125 °C | I _F = 10 A dI _F /dt = 200 A/μs V _R = 160 V | - | 35 | - | | | |
| Book receiver aurrent | 1 | T _J = 25 °C | | - | 1.9 | - | А | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | | - | 4.8 | - | A | | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 25 | - | | | |
| | Q _{rr} | T _J = 125 °C | | - | 78 | - | nC | | |

| THERMAL MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|----------------|-----------------------------------|--|--------------|------|------------|------------------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -65 | - | 175 | °C | |
| Thermal resistance, | er leg | | | - | - | 2.5 | | |
| junction to case | total evice | R _{thJC} | | - | - | 1.25 | | |
| Thermal resistance, junction to ambient per leg | | R _{thJA} | | - | - | 50 | °C/W | |
| Thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | | |
| Waight | | | | - | 2.0 | - | g | |
| Weight | | | | - | 0.07 | - | oz. | |
| Mounting torque | | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | |
| Marking device | | | Case style 3L TO-220AB | | MUR2 | 020CT | | |

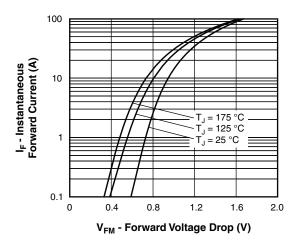
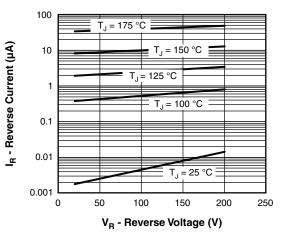
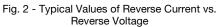


Fig. 1 - Maximum Forward Voltage Drop Characteristics





Document Number: 96201

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VS-MUR2020CT-M3

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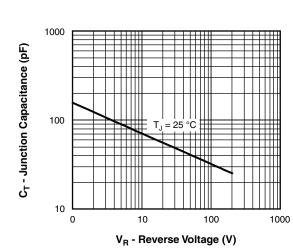


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

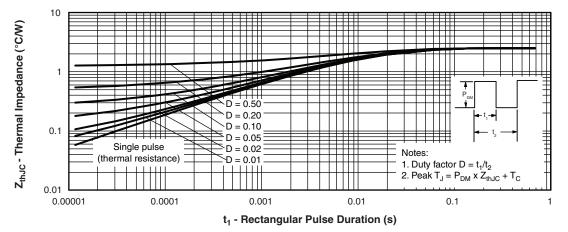
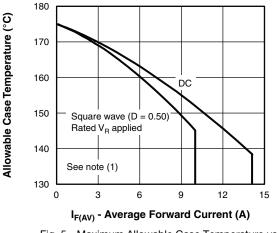
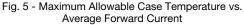
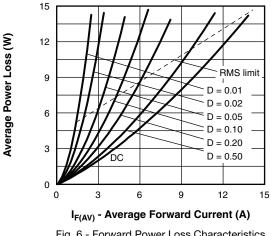


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics



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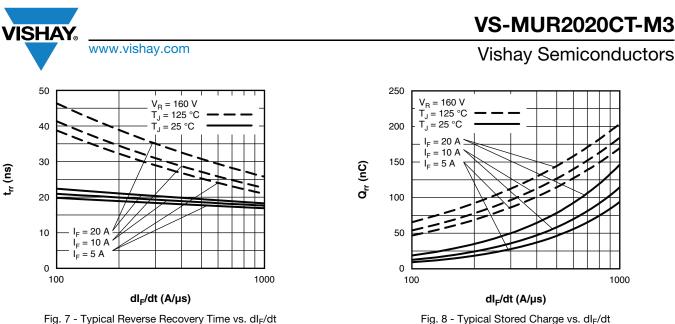


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

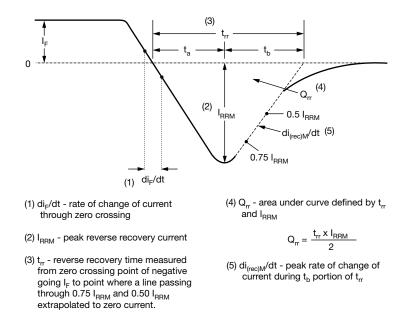


Fig. 9 - Reverse Recovery Waveform and Definitions

1000

VS-MUR2020CT-M3

20 CT M2

| Device code | VS- | MUR | 20 | 20 | СТ | -M3 | |
|-------------|-----|--------|-----------|------------|----------|-------|--|
| | | 2 | 3 | 4 | 5 | 6 | |
| | 1 - | | , | niconduc | | oduct | |
| | 2 - | | | UR serie | - | | |
| | 3 - | - Cur | rent rati | ng (20 = | = 20 A) | | |
| | 4 - | - Volt | tage rati | ng (20 = | = 200 V) | | |
| | 5 - | - CT | = cente | r tap (du | ial) | | |
| | 6 - | - Env | ironmer | ntal digit | : | | |

20

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | |
|---|----|------|-------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-MUR2020CT-M3 | 50 | 1000 | Antistatic plastic tube | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|--------------------------|--|--|--|--|--|
| Dimensions | www.vishay.com/doc?96154 | | | | | |
| Part marking information | www.vishay.com/doc?95028 | | | | | |
| SPICE model | www.vishay.com/doc?95272 | | | | | |

VS-MUR2020CT-M3

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ORDERING INFORMATION TABLE

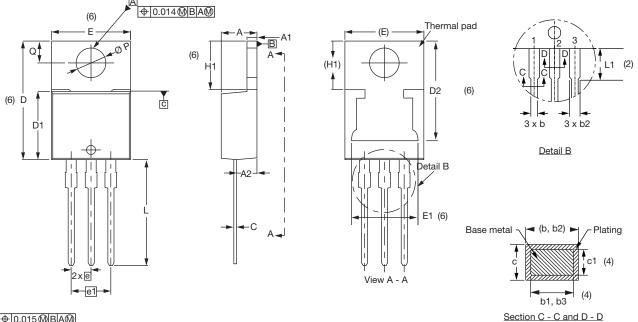
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Vishay Semiconductors

3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@





| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|---------|--------|--------|-------|-------|-------|
| STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.50 | 2.92 | 0.098 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.35 | 0.585 | 0.604 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|
| STWDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D2 | 11.68 | 13.30 | 0.460 | 0.524 | 6, 7 |
| Ш | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØР | 3.54 | 3.91 | 0.139 | 0.154 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| | | | | | |

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

- ⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 13-Jun-2019

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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 CRS04(T5L,TEMQ)
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